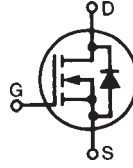


## TrenchT4™ Power MOSFET

## IXTA230N04T4 IXTP230N04T4

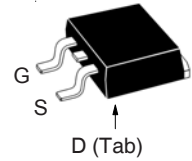
$$\begin{aligned} V_{DSS} &= 40V \\ I_{D25} &= 230A \\ R_{DS(on)} &\leq 2.9m\Omega \end{aligned}$$

N-Channel Enhancement Mode  
Avalanche Rated

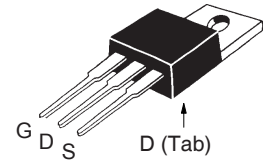


| Symbol     | Test Conditions                                                   | Maximum Ratings |                  |
|------------|-------------------------------------------------------------------|-----------------|------------------|
| $V_{DSS}$  | $T_J = 25^\circ\text{C to } 175^\circ\text{C}$                    | 40              | V                |
| $V_{DGR}$  | $T_J = 25^\circ\text{C to } 175^\circ\text{C}, R_{GS} = 1M\Omega$ | 40              | V                |
| $V_{GSM}$  | Transient                                                         | $\pm 15$        | V                |
| $I_{D25}$  | $T_C = 25^\circ\text{C}$                                          | 230             | A                |
| $I_{LRMS}$ | Lead Current Limit, RMS                                           | 160             | A                |
| $I_{DM}$   | $T_C = 25^\circ\text{C}$ , Pulse Width Limited by $T_{JM}$        | 700             | A                |
| $I_A$      | $T_C = 25^\circ\text{C}$                                          | 100             | A                |
| $E_{AS}$   | $T_C = 25^\circ\text{C}$                                          | 600             | mJ               |
| $P_D$      | $T_C = 25^\circ\text{C}$                                          | 340             | W                |
| $T_J$      |                                                                   | -55 ... +175    | $^\circ\text{C}$ |
| $T_{JM}$   |                                                                   | 175             | $^\circ\text{C}$ |
| $T_{stg}$  |                                                                   | -55 ... +175    | $^\circ\text{C}$ |
| $T_L$      | Maximum Lead Temperature for Soldering                            | 300             | $^\circ\text{C}$ |
| $T_{SOLD}$ | 1.6 mm (0.062in.) from Case for 10s                               | 260             | $^\circ\text{C}$ |
| $M_d$      | Mounting Torque (TO-220)                                          | 1.13 / 10       | Nm/lb.in.        |
| Weight     | TO-263                                                            | 2.5             | g                |
|            | TO-220                                                            | 3.0             | g                |

TO-263 AA (IXTA)



TO-220AB (IXTP)



G = Gate      D = Drain  
S = Source    Tab = Drain

### Features

- International Standard Packages
- 175°C Operating Temperature
- High Current Handling Capability
- Avalanche Rated
- Low  $R_{DS(on)}$

### Advantages

- Easy to Mount
- Space Savings
- High Power Density

### Applications

- Synchronous Buck Converters
- High Current Switching Power Supplies
- Battery Powered Electric Motors
- Resonant-Mode Power Supplies
- Electronics Ballast Application
- Class D Audio Amplifiers

| Symbol       | Test Conditions<br>( $T_J = 25^\circ\text{C}$ Unless Otherwise Specified) | Characteristic Values |      |                          |
|--------------|---------------------------------------------------------------------------|-----------------------|------|--------------------------|
|              |                                                                           | Min.                  | Typ. | Max.                     |
| $BV_{DSS}$   | $V_{GS} = 0V, I_D = 250\mu A$                                             | 40                    |      | V                        |
| $V_{GS(th)}$ | $V_{DS} = V_{GS}, I_D = 250\mu A$                                         | 2.0                   |      | 4.0 V                    |
| $I_{GSS}$    | $V_{GS} = \pm 15V, V_{DS} = 0V$                                           |                       |      | $\pm 200$ nA             |
| $I_{DSS}$    | $V_{DS} = V_{DSS}, V_{GS} = 0V$<br>$T_J = 150^\circ\text{C}$              |                       |      | 5 $\mu A$<br>250 $\mu A$ |
| $R_{DS(on)}$ | $V_{GS} = 10V, I_D = 0.5 \cdot I_{D25}$ , Notes 1,2                       |                       |      | 2.9 m $\Omega$           |

| Symbol       | Test Conditions<br>( $T_J = 25^\circ\text{C}$ , Unless Otherwise Specified)                                                                         | Characteristic Values |      |                        |
|--------------|-----------------------------------------------------------------------------------------------------------------------------------------------------|-----------------------|------|------------------------|
|              |                                                                                                                                                     | Min.                  | Typ. | Max.                   |
| $g_{fs}$     | $V_{DS} = 10\text{V}$ , $I_D = 60\text{A}$ , Note 1                                                                                                 | 100                   | 170  | S                      |
| $R_{Gi}$     | Gate Input Resistance                                                                                                                               |                       | 1.2  | $\Omega$               |
| $C_{iss}$    | $V_{GS} = 0\text{V}$ , $V_{DS} = 25\text{V}$ , $f = 1\text{MHz}$                                                                                    |                       | 7400 | pF                     |
| $C_{oss}$    |                                                                                                                                                     |                       | 1115 | pF                     |
| $C_{rss}$    |                                                                                                                                                     |                       | 760  | pF                     |
| $t_{d(on)}$  | <b>Resistive Switching Times</b><br>$V_{GS} = 10\text{V}$ , $V_{DS} = 0.5 \cdot V_{DSS}$ , $I_D = 0.5 \cdot I_{D25}$<br>$R_G = 10\Omega$ (External) |                       | 40   | ns                     |
| $t_r$        |                                                                                                                                                     |                       | 143  | ns                     |
| $t_{d(off)}$ |                                                                                                                                                     |                       | 85   | ns                     |
| $t_f$        |                                                                                                                                                     |                       | 82   | ns                     |
| $Q_{g(on)}$  | $V_{GS} = 10\text{V}$ , $V_{DS} = 0.5 \cdot V_{DSS}$ , $I_D = 0.5 \cdot I_{D25}$                                                                    |                       | 140  | nC                     |
| $Q_{gs}$     |                                                                                                                                                     |                       | 35   | nC                     |
| $Q_{gd}$     |                                                                                                                                                     |                       | 53   | nC                     |
| $R_{thJC}$   | TO-220                                                                                                                                              |                       | 0.50 | $0.44^\circ\text{C/W}$ |
| $R_{thCS}$   |                                                                                                                                                     |                       |      | $^\circ\text{C/W}$     |

#### Source-Drain Diode

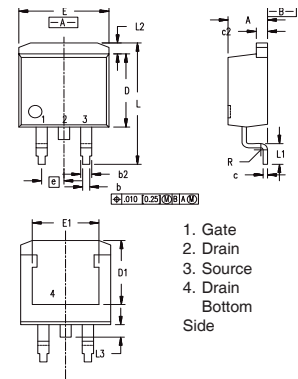
| Symbol   | Test Conditions<br>( $T_J = 25^\circ\text{C}$ , Unless Otherwise Specified)                            | Characteristic Values |      |       |
|----------|--------------------------------------------------------------------------------------------------------|-----------------------|------|-------|
|          |                                                                                                        | Min.                  | Typ. | Max.  |
| $I_S$    | $V_{GS} = 0\text{V}$                                                                                   |                       |      | 230 A |
| $I_{SM}$ | Repetitive, Pulse width limited by $T_{JM}$                                                            |                       |      | 920 A |
| $V_{SD}$ | $I_F = 100\text{A}$ , $V_{GS} = 0\text{V}$ , Note 1                                                    |                       |      | 1.4 V |
| $t_{rr}$ | $I_F = 115\text{A}$ , $V_{GS} = 0\text{V}$<br>$-di/dt = 100\text{A}/\mu\text{s}$<br>$V_R = 30\text{V}$ |                       | 32   | ns    |
| $I_{RM}$ |                                                                                                        |                       | 1.6  | A     |
| $Q_{RM}$ |                                                                                                        |                       | 25.6 | nC    |

Notes: 1. Pulse test,  $t \leq 300\mu\text{s}$ , duty cycle,  $d \leq 2\%$ .  
 2. On through-hole packages,  $R_{DS(on)}$  Kelvin test contact location must be 5mm or less from the package body.

#### ADVANCE TECHNICAL INFORMATION

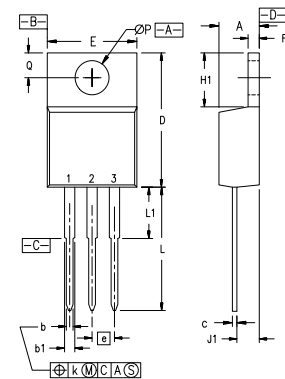
The product presented herein is under development. The Technical Specifications offered are derived from a subjective evaluation of the design, based upon prior knowledge and experience, and constitute a "considered reflection" of the anticipated result. IXYS reserves the right to change limits, test conditions, and dimensions without notice.

#### TO-263 (IXTA) Outline



| Dim. | Millimeter |       | Inches |      |
|------|------------|-------|--------|------|
|      | Min.       | Max.  | Min.   | Max. |
| A    | 4.06       | 4.83  | .160   | .190 |
| b    | 0.51       | 0.99  | .020   | .039 |
| b2   | 1.14       | 1.40  | .045   | .055 |
| c    | 0.40       | 0.74  | .016   | .029 |
| c2   | 1.14       | 1.40  | .045   | .055 |
| D    | 8.64       | 9.65  | .340   | .380 |
| D1   | 8.00       | 8.89  | .280   | .320 |
| E    | 9.65       | 10.41 | .380   | .405 |
| E1   | 6.22       | 8.13  | .270   | .320 |
| e    | 2.54       | BSC   | .100   | BSC  |
| L    | 14.61      | 15.88 | .575   | .625 |
| L1   | 2.29       | 2.79  | .090   | .110 |
| L2   | 1.02       | 1.40  | .040   | .055 |
| L3   | 1.27       | 1.78  | .050   | .070 |
| L4   | 0          | 0.13  | 0      | .005 |

#### TO-220 (IXTP) Outline



Pins: 1 - Gate 2 - Drain  
3 - Source

| SYM | INCHES |      | MILLIMETERS |       |
|-----|--------|------|-------------|-------|
|     | MIN    | MAX  | MIN         | MAX   |
| A   | .170   | .190 | 4.32        | 4.83  |
| b   | .025   | .040 | 0.64        | 1.02  |
| b1  | .045   | .065 | 1.15        | 1.65  |
| c   | .014   | .022 | 0.35        | 0.56  |
| D   | .580   | .630 | 14.73       | 16.00 |
| E   | .390   | .420 | 9.91        | 10.66 |
| e   | .100   | BSC  | 2.54        | BSC   |
| F   | .045   | .055 | 1.14        | 1.40  |
| H1  | .230   | .270 | 5.85        | 6.85  |
| J1  | .090   | .110 | 2.29        | 2.79  |
| k   | 0      | .015 | 0           | 0.38  |
| L   | .500   | .550 | 12.70       | 13.97 |
| L1  | .110   | .230 | 2.79        | 5.84  |
| ØP  | .139   | .161 | 3.53        | 4.08  |
| Q   | .100   | .125 | 2.54        | 3.18  |

IXYS Reserves The Right to Change Limits, Test Conditions, and Dimensions.

|                                                                                  |           |           |           |           |              |              |              |              |              |             |
|----------------------------------------------------------------------------------|-----------|-----------|-----------|-----------|--------------|--------------|--------------|--------------|--------------|-------------|
| IXYS MOSFETs and IGBTs are covered by one or more of the following U.S. patents: | 4,835,592 | 4,931,844 | 5,049,961 | 5,237,481 | 6,162,665    | 6,404,065 B1 | 6,683,344    | 6,727,585    | 7,005,734 B2 | 7,157,338B2 |
|                                                                                  | 4,860,072 | 5,017,508 | 5,063,307 | 5,381,025 | 6,259,123 B1 | 6,534,343    | 6,710,405 B2 | 6,759,692    | 7,063,975 B2 |             |
|                                                                                  | 4,881,106 | 5,034,796 | 5,187,117 | 5,486,715 | 6,306,728 B1 | 6,583,505    | 6,710,463    | 6,771,478 B2 | 7,071,537    |             |

Fig. 1. Output Characteristics @  $T_J = 25^\circ\text{C}$

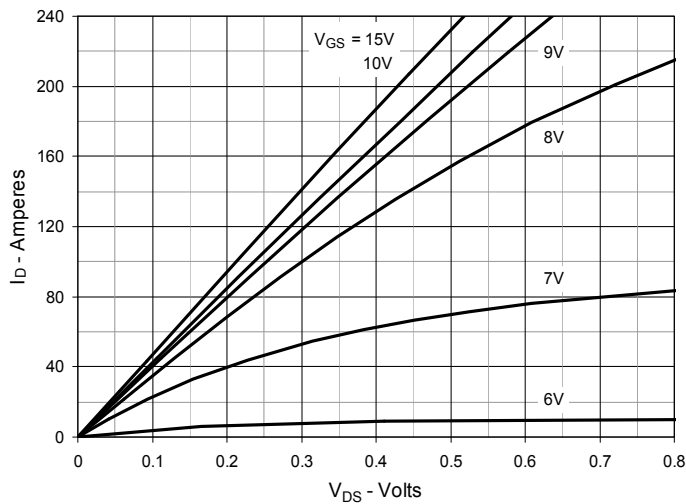


Fig. 2. Extended Output Characteristics @  $T_J = 25^\circ\text{C}$

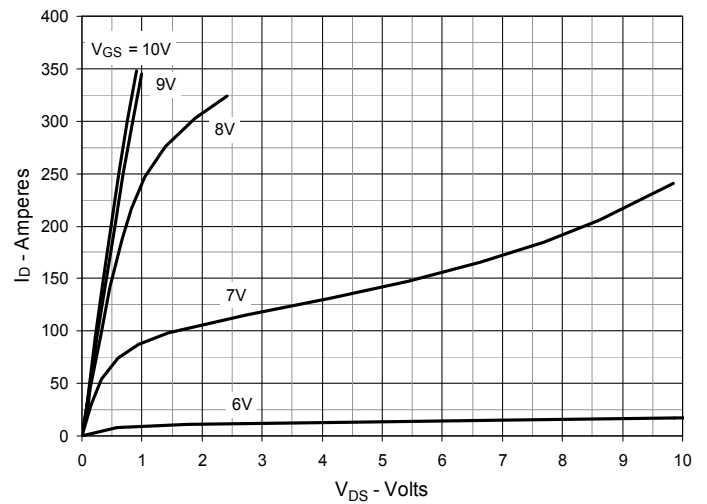


Fig. 3. Output Characteristics @  $T_J = 150^\circ\text{C}$

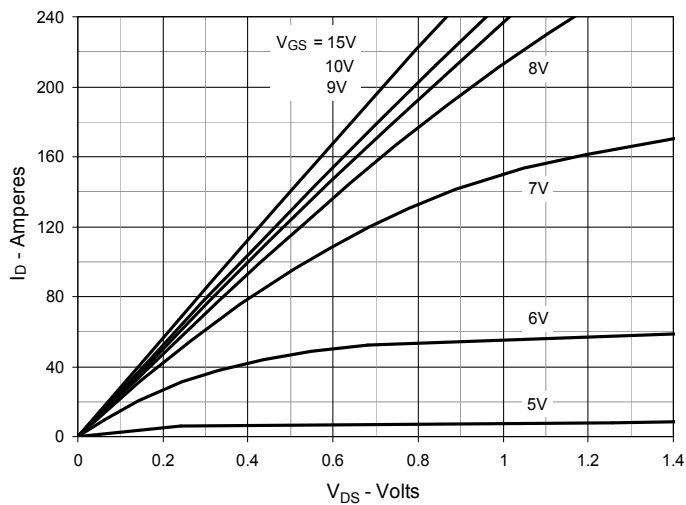


Fig. 4. Normalized  $R_{DS(on)}$  to  $I_D = 115\text{A}$  Value vs. Junction Temperature

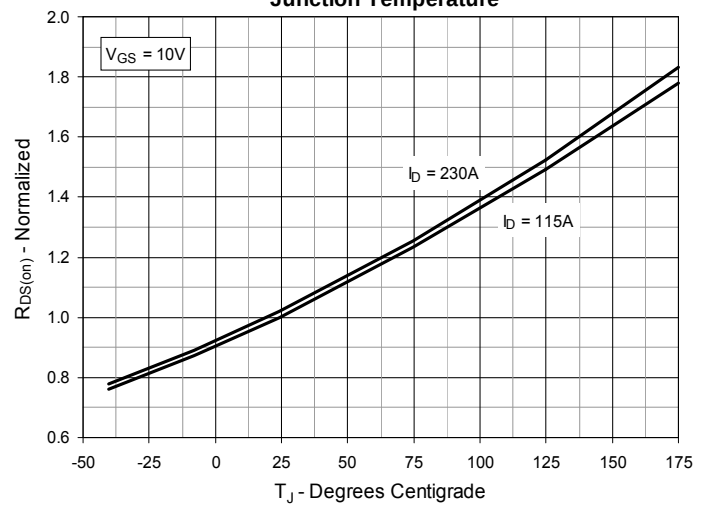


Fig. 5. Normalized  $R_{DS(on)}$  to  $I_D = 115\text{A}$  vs. Drain Current

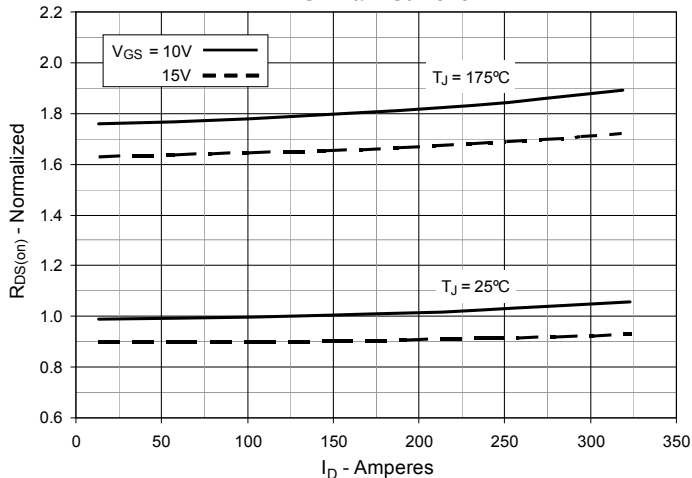
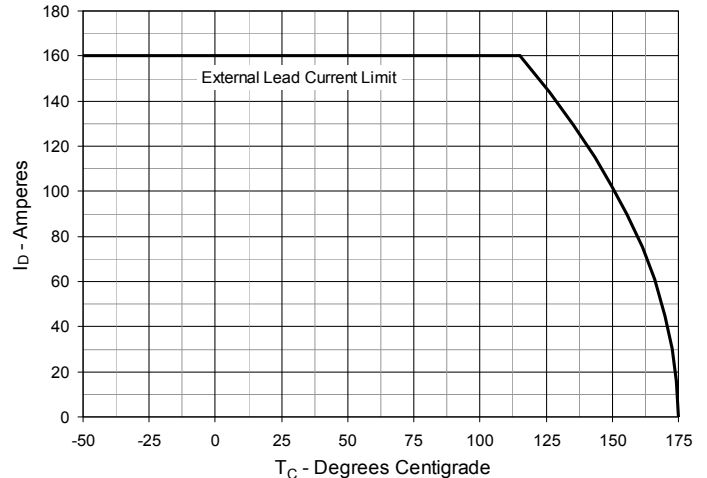
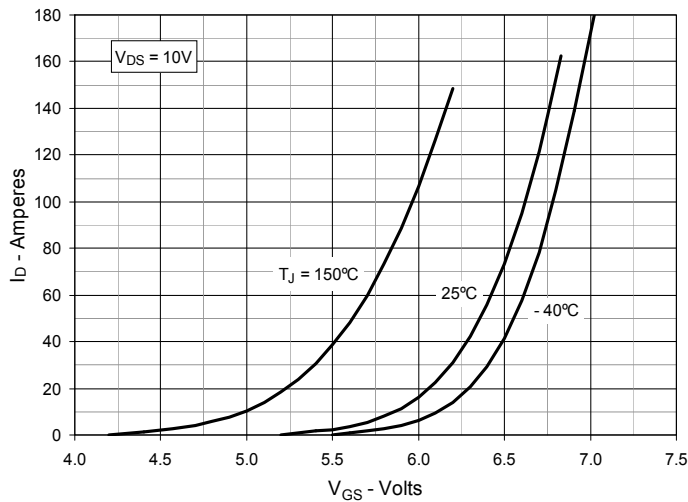


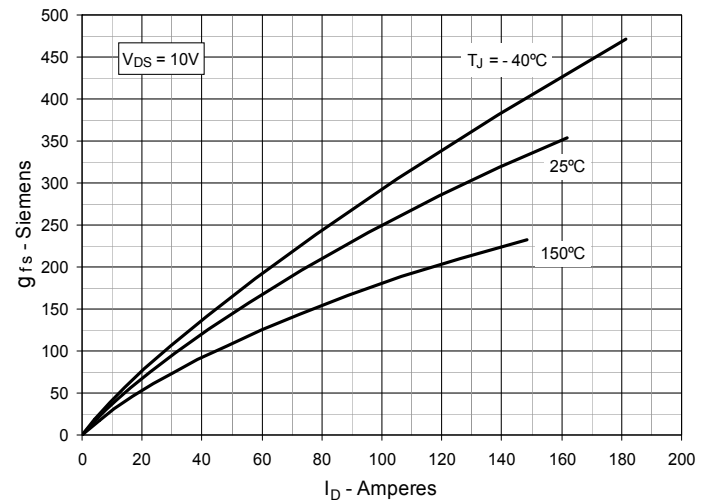
Fig. 6. Drain Current vs. Case Temperature



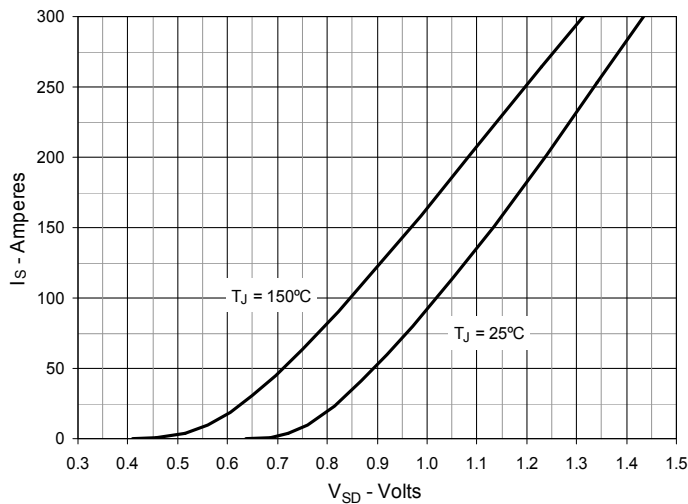
**Fig. 7. Input Admittance**



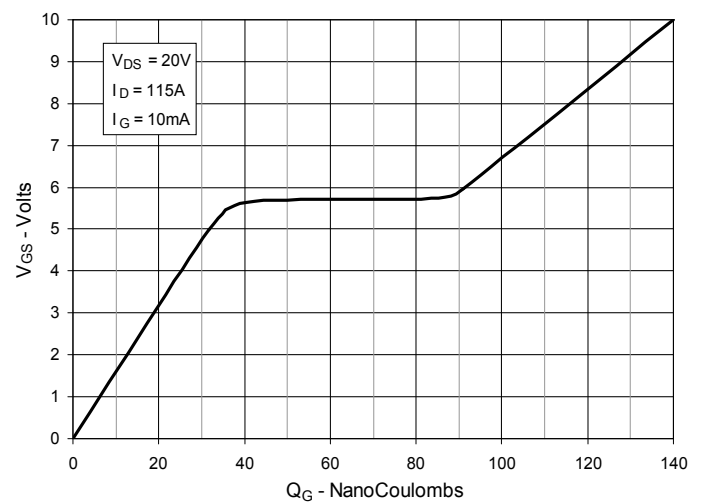
**Fig. 8. Transconductance**



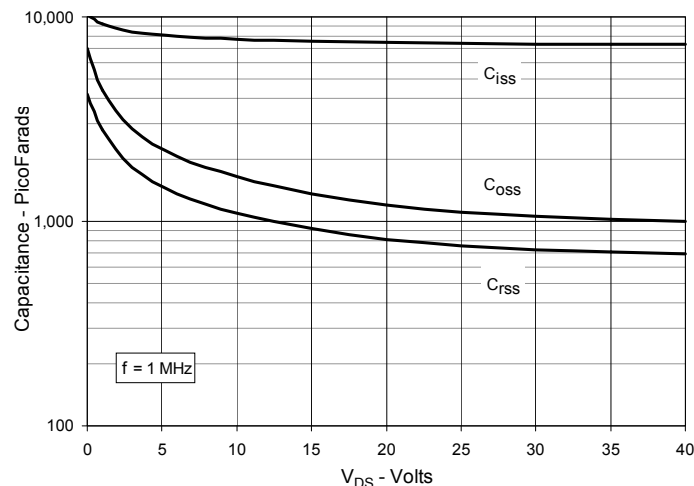
**Fig. 9. Forward Voltage Drop of Intrinsic Diode**



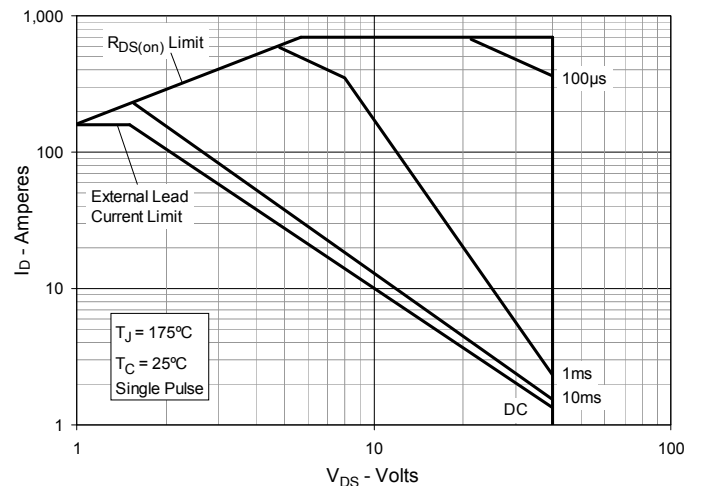
**Fig. 10. Gate Charge**



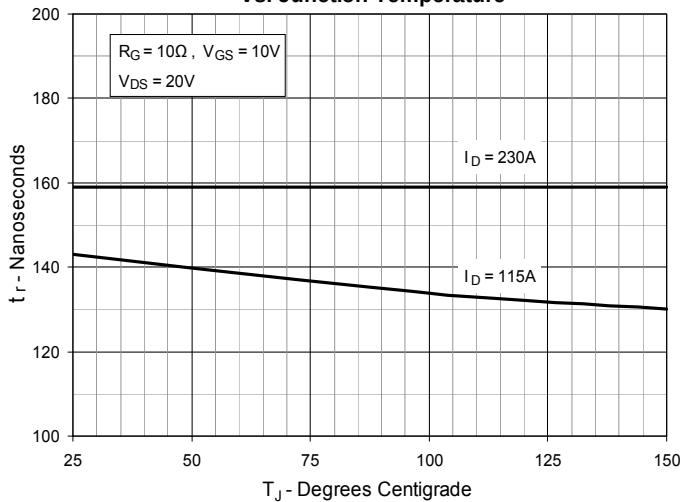
**Fig. 11. Capacitance**



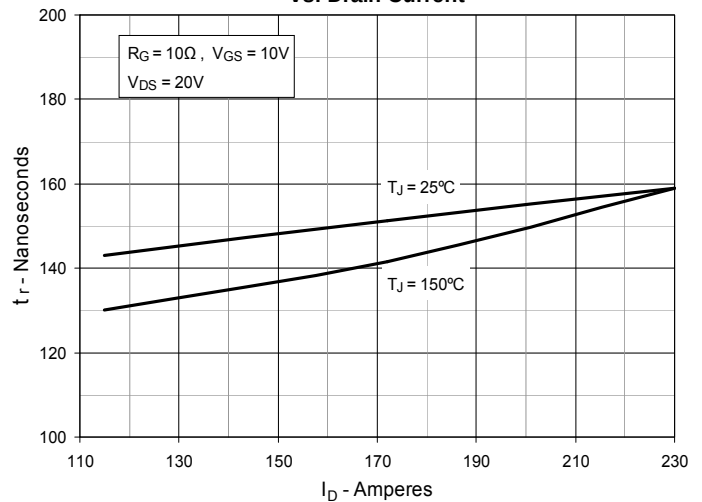
**Fig. 12. Forward-Bias Safe Operating Area**



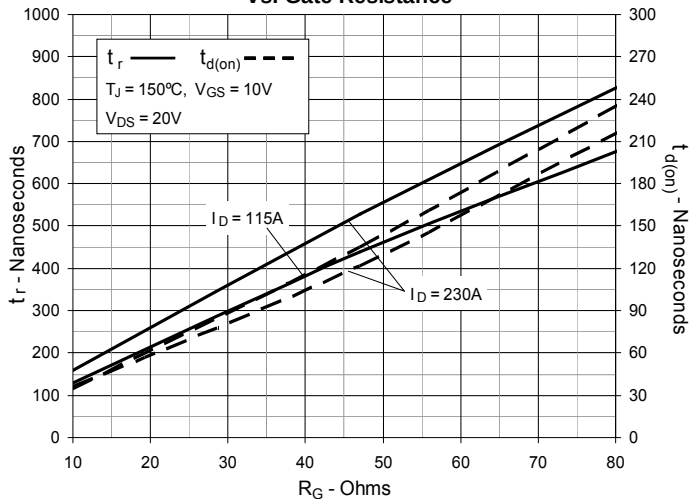
**Fig. 13. Resistive Turn-on Rise Time vs. Junction Temperature**



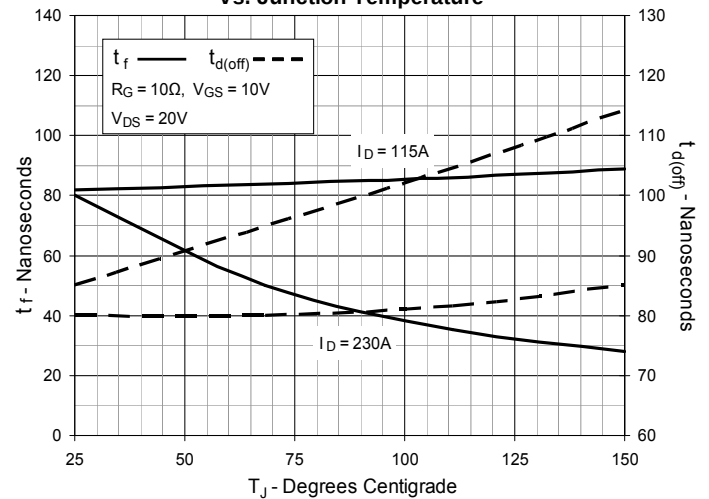
**Fig. 14. Resistive Turn-on Rise Time vs. Drain Current**



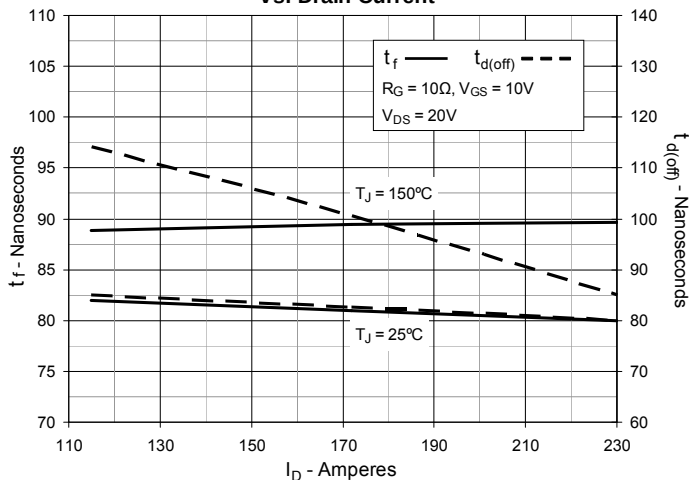
**Fig. 15. Resistive Turn-on Switching Times vs. Gate Resistance**



**Fig. 16. Resistive Turn-off Switching Times vs. Junction Temperature**



**Fig. 17. Resistive Turn-off Switching Times vs. Drain Current**



**Fig. 18. Resistive Turn-off Switching Times vs. Gate Resistance**

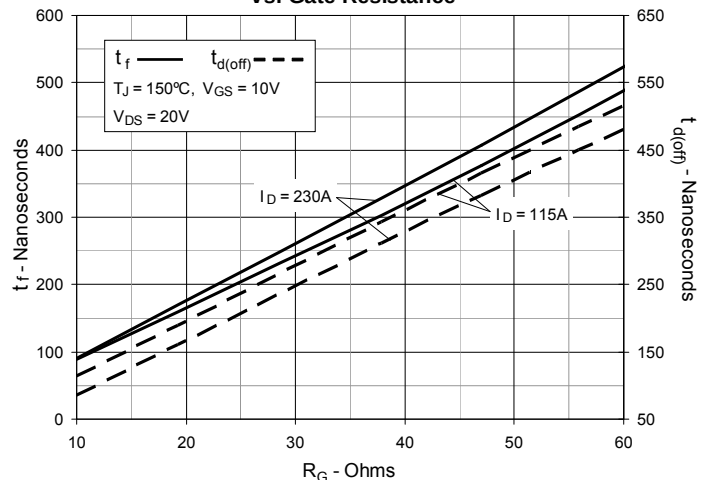
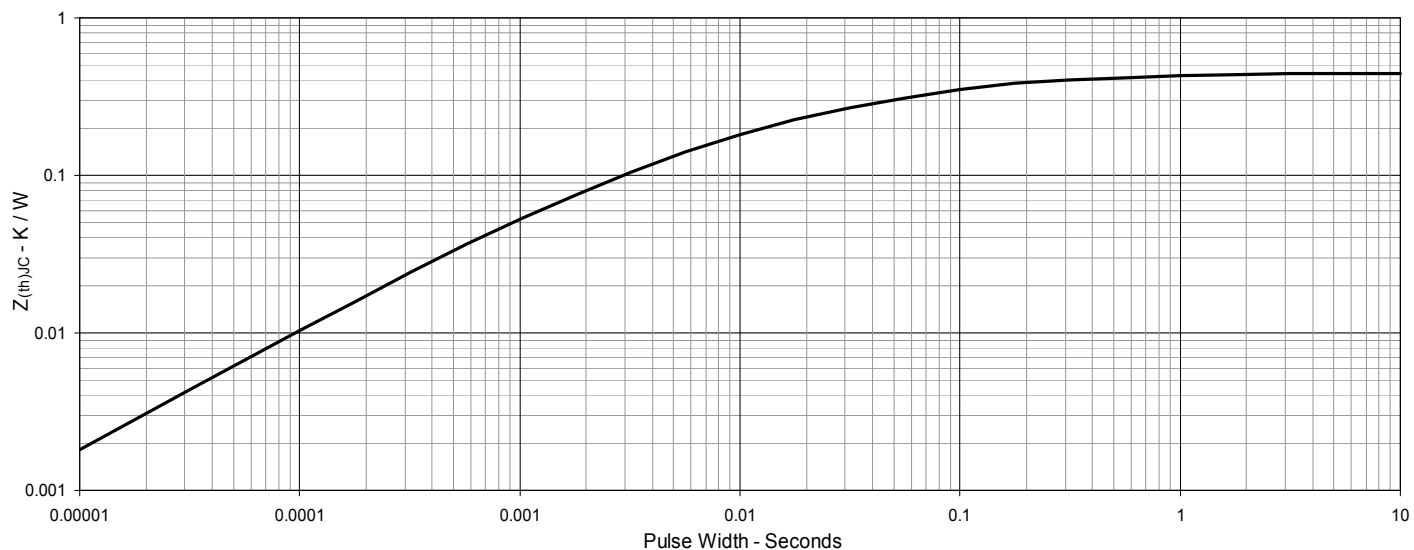


Fig. 19. Maximum Transient Thermal Impedance





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